## NSN 5961-01-051-6657

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-051-6657 **Internal Configuration:** Junction contact **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 20.0 reverse voltage, instantaneous and 15.0 forward voltage, peak **Current Rating Per Characteristic:** 5.00 milliamperes forward current, total rms absolute **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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